

| Doküman No      | MF.FR.003  |
|-----------------|------------|
| Revizyon Tarihi | 13.11.2024 |
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| Sayfa No        | 1 / 6      |

| NE 303 SOLID STATE PHYSICS |       |               |     |               |            |
|----------------------------|-------|---------------|-----|---------------|------------|
| <b>Course Code</b>         |       | Course Na     | ame | Sem           | ester      |
| NE 303                     | SOLIE | STATE PHYSICS |     | Fall 🗵 Spring | ☐ Summer ☐ |
|                            |       | Hours         |     | Credit        | ECTS       |
| Theory                     |       | Practice      | Lab | 2             | F          |
| 3                          |       | 0             | 0   | 3             | 5          |

| Course Details    |  |
|-------------------|--|
| Department        | Nanotechnology   |
| Course Language   | English  |
| Course Level      | Undergraduate ⊠ Graduate □   |
| Mode of Delivery  | Face to Face ⊠ Online □ Hybrid □   |
| Course Type       | Compulsory ⊠ Elective □  |
| Lecturer(s)       |  |
| Course Objectives | <ul> <li>Understand the crystal structures and symmetries in solids.</li> <li>Analyze bonding mechanisms and interatomic forces.</li> <li>Learn about electron behavior in periodic potentials and energy band structures.</li> <li>Gain insight into phonons and thermal properties of solids.</li> <li>Explore electrical, thermal, and magnetic properties of solids with applications to nanomaterials.</li> <li>Connect quantum phenomena to the physical behavior of nanostructures.</li> </ul>  |
| Course Content    | <ul> <li>Introduction to solid state physics and its relevance to nanotechnology: Basic concepts, history, and the role of solid state physics in understanding material properties at the nanoscale.</li> <li>Crystal structure and symmetry: Crystal systems, Bravais lattices, unit cells, lattice directions and planes (Miller indices), symmetry operations.</li> <li>X-ray diffraction and reciprocal lattice: Bragg's law, reciprocal space, Ewald construction, and structure factor.</li> <li>Bonding in solids: Types of interatomic bonding (ionic, covalent, metallic, van der Waals, hydrogen bonding), cohesive energy, potential energy curves.</li> <li>Lattice dynamics and phonons: Vibrations of monoatomic and diatomic chains, phonon dispersion, density of states, specific heat (Einstein and Debye models).</li> <li>Thermal properties of solids: Thermal expansion, thermal conductivity, phonon-phonon scattering, thermal resistance.</li> <li>Free electron theory of metals: Drude and Sommerfeld models,</li> </ul> |



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|                                | <ul> <li>electrical and thermal conductivity, limitations of classical models.</li> <li>Band theory of solids: Bloch's theorem, Kronig-Penney model, energy bands, Brillouin zones, effective mass of electrons and holes.</li> <li>Semiconductors: Intrinsic and extrinsic semiconductors, Fermi level, carrier concentration, conductivity, doping.</li> <li>Nanostructured semiconductors: Quantum wells, quantum wires, quantum dots, size effects on electronic and optical properties.</li> <li>Dielectric properties: Polarization mechanisms, dielectric constant, ferroelectric materials, applications in nanodevices.</li> <li>Magnetic properties of solids: Diamagnetism, paramagnetism, ferromagnetism, nanomagnetism, and magnetic storage technologies.</li> <li>Superconductivity: Basic properties, Meissner effect, Cooper pairs, types of superconductors, superconductivity in nanoscale systems.</li> <li>Low-dimensional systems: 2D materials (e.g., graphene), 1D nanowires, and their unique physical properties and applications.</li> </ul> |
|--------------------------------|---|
|                                | manovines, and their anique physical properties and applications.   |
| Course Method/<br>Techniques   | Lecture ⊠ Question & Answer ⊠ Presentation □ Discussion □   |
| Prerequisites/<br>Corequisites |   |
| Work Placement(s)              |   |
| Textbook/References/Ma         | terials   |
| 2. N. W. Ashcr                 | tel, Introduction to Solid State Physics, Wiley, 8th Edition. roft & N. D. Mermin, Solid State Physics, Cengage. , Principles of Electronic Materials and Devices, McGraw-Hill.   |

| Course Category                |             |            |             |
|--------------------------------|-------------|------------|-------------|
| Mathematics and Basic Sciences | $\boxtimes$ | Education  |             |
| Engineering                    | $\boxtimes$ | Science    | $\boxtimes$ |
| Engineering Design             |             | Health     |             |
| Social Sciences                |             | Profession |             |

| Weekly Schedule |   |                 |
|-----------------|---|-----------------|
| No              | Topics  | Materials/Notes |
| 1               | Introduction to Solid State Physics and Overview of Nanotechnology Applications | Lecture notes   |
| 2               | Crystal Structures: Lattices, Basis, Unit Cells, Bravais Lattices               | Lecture notes   |
| 3               | X-ray Diffraction and Reciprocal Lattice  | Lecture notes   |
| 4               | Bonding in Solids: Ionic, Covalent, Metallic, van der Waals                     | Lecture notes   |
| 5               | Elastic Properties and Crystal Binding  | Lecture notes   |



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| 6  | Phonons and Lattice Vibrations                             | Lecture notes |
|----|--|---------------|
| 7  | Thermal Properties: Specific Heat and Thermal Conductivity | Lecture notes |
| 8  | Midterm Exam   |               |
| 9  | Free Electron Theory and Electrical Conductivity           | Lecture notes |
| 10 | Band Theory of Solids: Bloch's Theorem and Brillouin Zones | Lecture notes |
| 11 | Semiconductors: Intrinsic and Extrinsic                    | Lecture notes |
| 12 | Nanostructured Semiconductors and Quantum Confinement      | Lecture notes |
| 13 | Dielectric Properties and Ferroelectrics                   | Lecture notes |
| 14 | Magnetic Properties and Applications in Nanomagnetism      | Lecture notes |
| 15 | Superconductivity and Low-Dimensional Systems              | Lecture notes |
| 16 | Final Exam   |               |



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| Assessment Methods and Criteria                          |          |            |  |
|--|----------|------------|--|
| In-term studies  | Quantity | Percentage |  |
| Attendance   | 14       | 10         |  |
| Lab  |          |            |  |
| Practice   |          |            |  |
| Fieldwork  |          |            |  |
| Course-specific internship                               |          |            |  |
| Quiz/Studio/Criticize                                    |          |            |  |
| Homework   | 2        | 10         |  |
| Presentation / Seminar                                   | 1        | 5          |  |
| Project  |          |            |  |
| Report   |          |            |  |
| Seminar  |          |            |  |
| Midterm Exam   | 1        | 25         |  |
| Final Exam   | 1        | 50         |  |
|  | Total    | 100%       |  |
| Contribution of Midterm Studies to Success Grade         |          | 50         |  |
| Contribution of End of Semester Studies to Success Grade |          | 50         |  |
|  | Total    | 100%       |  |

| ECTS Allocated Based on Student Workload  |          |                |                |
|---|----------|----------------|----------------|
| Activities                                | Quantity | Duration (Hrs) | Total Workload |
| Course Hours                              | 14       | 3              | 42             |
| Lab                                       |          |                |                |
| Practice                                  |          |                |                |
| Fieldwork                                 |          |                |                |
| Course-specific Work Placement            |          |                |                |
| Out-of-class study time                   | 14       | 2              | 28             |
| Quiz/Studio/Criticize                     |          |                |                |
| Homework                                  | 2        | 5              | 10             |
| Presentation / Seminar                    | 1        | 5              | 5              |
| Project                                   |          |                |                |
| Report                                    |          |                |                |
| Midterm Exam and Preparation for Midterm  | 1        | 25             | 25             |
| Final Exam and Preparation for Final Exam | 1        | 30             | 30             |
| Total Workload                            |          |                | 125            |
| Total Workload / 25                       |          |                | 5              |
| ECTS Credit                               |          |                | 5              |



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| Course L | ourse Learning Outcomes  |  |  |  |  |  |  |  |
|----------|--|--|--|--|--|--|--|--|
| No       | Outcome  |  |  |  |  |  |  |  |
| L1       | Identify and describe the basic crystal structures, unit cells, and symmetry operations in solids.                                   |  |  |  |  |  |  |  |
| L2       | Analyze diffraction patterns and calculate interplanar distances using X-ray diffraction principles.                                 |  |  |  |  |  |  |  |
| L3       | Explain the origin of bonding in solids and relate it to mechanical and thermal properties.  |  |  |  |  |  |  |  |
| L4       | Describe and interpret lattice vibrations and phonons, and their influence on thermal conductivity and heat capacity.                |  |  |  |  |  |  |  |
| L5       | Apply band theory to distinguish between conductors, semiconductors, and insulators, and analyze carrier behavior in semiconductors. |  |  |  |  |  |  |  |
| L6       | Evaluate how nanoscale effects modify electrical, thermal, and magnetic properties of materials in comparison to bulk materials.     |  |  |  |  |  |  |  |

|       | Contribution of Course Learning Outcomes to Program Competencies/Outcomes                       |     |      |     |      |     |      |     |      |     |      |     |     |      |     |     |     |     |     |     |      |     |      |     |       |      |      |       |      |   |
|-------|---|-----|------|-----|------|-----|------|-----|------|-----|------|-----|-----|------|-----|-----|-----|-----|-----|-----|------|-----|------|-----|-------|------|------|-------|------|---|
| Contr | Contribution Level: 1: Very Slight, 2: Slight, 3: Moderate, 4: Significant, 5: Very Significant |     |      |     |      |     |      |     |      |     |      |     |     |      |     |     |     |     |     |     |      |     |      |     |       |      |      |       |      |   |
|       | PO-1  |     | PO-2 |     | PO-3 |     | PO-4 |     | PO-5 |     | PO-6 |     |     | PO-7 |     |     |     |     |     |     | PO-8 |     | PO-9 |     | PO-10 |      |      | PO-11 |      |   |
| #     | 1.1   | 1.2 | 2.1  | 2.2 | 3.1  | 3.2 | 4.1  | 4.2 | 5.1  | 5.2 | 5.3  | 6.1 | 6.2 | 6.3  | 7.1 | 7.2 | 7.3 | 7.4 | 7.5 | 7.6 | 8.1  | 8.2 | 9.1  | 9.2 | 10.1  | 10.2 | 10.3 | 11.1  | 11.2 | # |
| L1    | Х   | Х   |      |     |      |     |      |     |      |     |      |     |     | Х    |     |     |     |     |     |     |      |     |      |     |       |      |      |       |      | - |
| L2    |   | Х   | Х    |     |      |     | Х    |     |      |     |      |     |     | Х    |     |     |     |     |     |     |      |     |      |     |       |      |      |       |      | - |
| L3    | Х   | Х   | Х    |     |      |     |      |     |      |     |      |     |     | Х    |     |     |     |     |     |     |      |     |      |     |       |      |      |       |      | - |
| L4    | Х   | Х   |      | Х   |      |     |      |     |      |     | Х    |     |     | Х    |     |     |     |     |     |     |      |     |      |     |       |      |      |       |      | - |
| L5    | Х   | Х   | Χ    |     |      |     |      | Χ   |      |     |      |     |     | Х    |     |     |     |     |     |     |      |     |      |     |       |      |      |       |      | - |
| L6    | Х   | Х   | Χ    |     |      |     |      |     |      |     | Χ    |     |     | Х    |     |     |     |     |     |     |      |     |      |     |       |      |      | Χ     |      | - |
|       |   |     |      |     |      |     |      |     |      |     |      |     |     |      |     |     |     |     |     |     |      |     |      |     |       |      |      | Tot   | al=  | - |

- 1.1. Adequate knowledge in mathematics, natural sciences, and subjects specific to the relevant engineering discipline.
- 1.2. Ability to apply theoretical and practical knowledge in these areas to solve complex engineering problems.
- 2.1. Ability to identify, formulate, and solve complex engineering problems.
- 2.2. Ability to select and apply appropriate analysis and modeling methods for this purpose.
- 3.1. Ability to design a complex system, process, device, or product to meet specific requirements under realistic constraints and conditions.
- 3.2. Ability to apply modern design methodologies for this purpose.
- 4.1. Ability to select and use modern techniques and tools necessary for analyzing and solving complex problems encountered in engineering practice.
- 4.2. Ability to effectively utilize information technologies.



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- 5.1. Ability to design experiments to investigate complex engineering problems or discipline-specific research topics.
- 5.2. Ability to conduct experiments.
- 5.3. Ability to collect data, analyze results, and interpret findings.
- 6.1. Ability to work effectively in intra-disciplinary teams.
- 6.2. Ability to work effectively in multi-disciplinary teams.
- 6.3. Ability to work independently.
- 7.1. Ability to communicate effectively both orally and in writing.
- 7.2. Knowledge of at least one foreign language.
- 7.3. Ability to write and comprehend effective reports, and to prepare design and production documentation.
- 7.4. Ability to deliver effective presentations.
- 7.5. Ability to give and receive clear and understandable instructions.
- 8.1. Awareness of the necessity for lifelong learning.
- 8.2. Ability to access information, follow developments in science and technology, and continuously renew oneself.
- 9.1. Acting in accordance with ethical principles and having professional and ethical responsibility.
- 9.2. Knowledge about standards used in engineering practices.
- 10.1. Knowledge of business practices such as project management, risk management, and change management.
- 10.2. Awareness of entrepreneurship and innovation.
- 10.3. Knowledge about sustainable development.
- 11.1. Knowledge of the global and societal impacts of engineering practices on health, environment, and safety, and understanding of contemporary issues reflected in the field of engineering.
- 11.2. Awareness of the legal consequences of engineering solutions.